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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded - Microcontrollers</u>"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	24MHz
Connectivity	I ² C, IrDA, LINbus, Microwire, SmartCard, SPI, SSP, UART/USART
Peripherals	Brown-out Detect/Reset, CapSense, LCD, LVD, POR, PWM, WDT
Number of I/O	34
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 5.5V
Data Converters	A/D 16x10b Slope; D/A 2xIDAC
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	40-UFQFN Exposed Pad
Supplier Device Package	40-QFN (6x6)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/cy8c4125lqi-s413t



Reset

The PSoC 4100S can be reset from a variety of sources including a software reset. Reset events are asynchronous and guarantee reversion to a known state. The reset cause is recorded in a register, which is sticky through reset and allows software to determine the cause of the reset. An XRES pin is reserved for external reset by asserting it active low. The XRES pin has an internal pull-up resistor that is always enabled.

Analog Blocks

12-bit SAR ADC

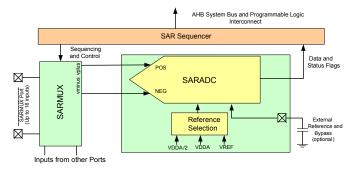
The 12-bit, 1-Msps SAR ADC can operate at a maximum clock rate of 18 MHz and requires a minimum of 18 clocks at that frequency to do a 12-bit conversion.

The Sample-and-Hold (S/H) aperture is programmable allowing the gain bandwidth requirements of the amplifier driving the SAR inputs, which determine its settling time, to be relaxed if required. It is possible to provide an external bypass (through a fixed pin location) for the internal reference amplifier.

The SAR is connected to a fixed set of pins through an 8-input sequencer. The sequencer cycles through selected channels autonomously (sequencer scan) with zero switching overhead (that is, aggregate sampling bandwidth is equal to 1 Msps whether it is for a single channel or distributed over several channels). The sequencer switching is effected through a state machine or through firmware driven switching. A feature provided by the sequencer is buffering of each channel to reduce CPU interrupt service requirements. To accommodate signals with varying source impedance and frequency, it is possible to have different sample times programmable for each channel. Also, signal range specification through a pair of range registers (low and high range values) is implemented with a corresponding out-of-range interrupt if the digitized value exceeds the programmed range; this allows fast detection of out-of-range values without the necessity of having to wait for a sequencer scan to be completed and the CPU to read the values and check for out-of-range values in software.

The SAR is not available in Deep Sleep mode as it requires a high-speed clock (up to 18 MHz). The SAR operating range is 1.71 V to 5.5 V.

Figure 3. SAR ADC



Two Opamps (Continuous-Time Block; CTB)

The PSoC 4100S has two opamps with Comparator modes which allow most common analog functions to be performed on-chip eliminating external components; PGAs, Voltage

Buffers, Filters, Trans-Impedance Amplifiers, and other functions can be realized, in some cases with external passives. saving power, cost, and space. The on-chip opamps are designed with enough bandwidth to drive the Sample-and-Hold circuit of the ADC without requiring external buffering.

Low-power Comparators (LPC)

The PSoC 4100S has a pair of low-power comparators, which can also operate in Deep Sleep modes. This allows the analog system blocks to be disabled while retaining the ability to monitor external voltage levels during low-power modes. The comparator outputs are normally synchronized to avoid metastability unless operating in an asynchronous power mode where the system wake-up circuit is activated by a comparator switch event. The LPC outputs can be routed to pins.

Current DACs

The PSoC 4100S has two IDACs, which can drive any of the pins on the chip. These IDACs have programmable current ranges.

Analog Multiplexed Buses

The PSoC 4100S has two concentric independent buses that go around the periphery of the chip. These buses (called amux buses) are connected to firmware-programmable analog switches that allow the chip's internal resources (IDACs, comparator) to connect to any pin on the I/O Ports.

Programmable Digital Blocks

The Programmable I/O (Smart I/O) block is a fabric of switches and LUTs that allows Boolean functions to be performed in signals being routed to the pins of a GPIO port. The Smart I/O can perform logical operations on input pins to the chip and on signals going out as outputs.

Fixed Function Digital

Timer/Counter/PWM (TCPWM) Block

The TCPWM block consists of a 16-bit counter with user-programmable period length. There is a capture register to record the count value at the time of an event (which may be an I/O event), a period register that is used to either stop or auto-reload the counter when its count is equal to the period register, and compare registers to generate compare value signals that are used as PWM duty cycle outputs. The block also provides true and complementary outputs with programmable offset between them to allow use as dead-band programmable complementary PWM outputs. It also has a Kill input to force outputs to a predetermined state; for example, this is used in motor drive systems when an over-current state is indicated and the PWM driving the FETs needs to be shut off immediately with no time for software intervention. There are five TCPWM blocks in the PSoC 4100S.

Serial Communication Block (SCB)

The PSoC 4100S has three serial communication blocks, which can be programmed to have SPI, I2C, or UART functionality.

I²C Mode: The hardware I²C block implements a full multi-master and slave interface (it is capable of multi-master arbitration). This block is capable of operating at speeds of up to 400 kbps (Fast Mode) and has flexible buffering options to reduce interrupt overhead and latency for the CPU. It also



supports EZI2C that creates a mailbox address range in the memory of the PSoC 4100S and effectively reduces I²C communication to reading from and writing to an array in memory. In addition, the block supports an 8-deep FIFO for receive and transmit which, by increasing the time given for the CPU to read data, greatly reduces the need for clock stretching caused by the CPU not having read data on time.

The I^2C peripheral is compatible with the I^2C Standard-mode and Fast-mode devices as defined in the NXP I^2C -bus specification and user manual (UM10204). The I^2C bus I/O is implemented with GPIO in open-drain modes.

The PSoC 4100S is not completely compliant with the I²C spec in the following respect:

■ GPIO cells are not overvoltage tolerant and, therefore, cannot be hot-swapped or powered up independently of the rest of the I²C system.

UART Mode: This is a full-feature UART operating at up to 1 Mbps. It supports automotive single-wire interface (LIN), infrared interface (IrDA), and SmartCard (ISO7816) protocols, all of which are minor variants of the basic UART protocol. In addition, it supports the 9-bit multiprocessor mode that allows addressing of peripherals connected over common RX and TX lines. Common UART functions such as parity error, break detect, and frame error are supported. An 8-deep FIFO allows much greater CPU service latencies to be tolerated.

SPI Mode: The SPI mode supports full Motorola SPI, TI SSP (adds a start pulse used to synchronize SPI Codecs), and National Microwire (half-duplex form of SPI). The SPI block can use the FIFO.

GPIO

The PSoC 4100S has up to 36 GPIOs. The GPIO block implements the following:

- Eight drive modes:
 - ☐ Analog input mode (input and output buffers disabled)
 - □ Input only
 - ☐ Weak pull-up with strong pull-down
 - □ Strong pull-up with weak pull-down
 - □ Open drain with strong pull-down
 - □ Open drain with strong pull-up
 - $\ensuremath{\square}$ Strong pull-up with strong pull-down
 - □ Weak pull-up with weak pull-down
- Input threshold select (CMOS or LVTTL).
- Individual control of input and output buffer enabling/disabling in addition to the drive strength modes
- Selectable slew rates for dV/dt related noise control to improve EMI

The pins are organized in logical entities called ports, which are 8-bit in width (less for Ports 2 and 3). During power-on and reset, the blocks are forced to the disable state so as not to crowbar any inputs and/or cause excess turn-on current. A multiplexing network known as a high-speed I/O matrix is used to multiplex between various signals that may connect to an I/O pin.

Data output and pin state registers store, respectively, the values to be driven on the pins and the states of the pins themselves.

Every I/O pin can generate an interrupt if so enabled and each I/O port has an interrupt request (IRQ) and interrupt service routine (ISR) vector associated with it (5 for PSoC 4100S).

Special Function Peripherals

CapSense

CapSense is supported in the PSoC 4100S through a CapSense Sigma-Delta (CSD) block that can be connected to any pins through an analog multiplex bus via analog switches. CapSense function can thus be provided on any available pin or group of pins in a system under software control. A PSoC Creator component is provided for the CapSense block to make it easy for the user.

Shield voltage can be driven on another analog multiplex bus to provide water-tolerance capability. Water tolerance is provided by driving the shield electrode in phase with the sense electrode to keep the shield capacitance from attenuating the sensed input. Proximity sensing can also be implemented.

The CapSense block has two IDACs, which can be used for general purposes if CapSense is not being used (both IDACs are available in that case) or if CapSense is used without water tolerance (one IDAC is available).

The CapSense block also provides a 10-bit Slope ADC function which can be used in conjunction with the CapSense function.

The CapSense block is an advanced, low-noise, programmable block with programmable voltage references and current source ranges for improved sensitivity and flexibility. It can also use an external reference voltage. It has a full-wave CSD mode that alternates sensing to VDDA and ground to null out power-supply related noise.

LCD Segment Drive

The PSoC 4100S has an LCD controller, which can drive up to 4 commons and up to 32 segments. It uses full digital methods to drive the LCD segments requiring no generation of internal LCD voltages. The two methods used are referred to as Digital Correlation and PWM. Digital Correlation pertains to modulating the frequency and drive levels of the common and segment signals to generate the highest RMS voltage across a segment to light it up or to keep the RMS signal to zero. This method is good for STN displays but may result in reduced contrast with TN (cheaper) displays. PWM pertains to driving the panel with PWM signals to effectively use the capacitance of the panel to provide the integration of the modulated pulse-width to generate the desired LCD voltage. This method results in higher power consumption but can result in better results when driving TN displays. LCD operation is supported during Deep Sleep refreshing a small display buffer (4 bits; 1 32-bit register per port).



Pinouts

The following table provides the pin list for PSoC 4100S for the 48-pin TQFP, 44-pin TQFP, 40-pin QFN, 32-pin QFN, and 35-ball CSP packages. All port pins support GPIO.

Table 1. Pin List

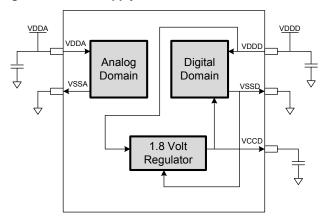
48-1	TQFP	44-	TQFP	40	-QFN	32	-QFN	35	5-CSP
Pin	Name	Pin	Name	Pin	Name	Pin	Name	Pin	Name
28	P0.0	24	P0.0	22	P0.0	17	P0.0	C3	P0.0
29	P0.1	25	P0.1	23	P0.1	18	P0.1	A5	P0.1
30	P0.2	26	P0.2	24	P0.2	19	P0.2	A4	P0.2
31	P0.3	27	P0.3	25	P0.3	20	P0.3	A3	P0.3
32	P0.4	28	P0.4	26	P0.4	21	P0.4	В3	P0.4
33	P0.5	29	P0.5	27	P0.5	22	P0.5	A6	P0.5
34	P0.6	30	P0.6	28	P0.6	23	P0.6	B4	P0.6
35	P0.7	31	P0.7	29	P0.7			B5	P0.7
36	XRES	32	XRES	30	XRES	24	XRES	В6	XRES
37	VCCD	33	VCCD	31	VCCD	25	VCCD	A7	VCCD
38	VSSD			DN	VSSD	26	VSSD	В7	VSS
39	VDDD	34	VDDD	32	VDDD			C7	VDD
40	VDDA	35	VDDA	33	VDDA	27	VDD	C7	VDD
41	VSSA	36	VSSA	34	VSSA	28	VSSA	В7	VSS
42	P1.0	37	P1.0	35	P1.0	29	P1.0	C4	P1.0
43	P1.1	38	P1.1	36	P1.1	30	P1.1	C5	P1.1
44	P1.2	39	P1.2	37	P1.2	31	P1.2	C6	P1.2
45	P1.3	40	P1.3	38	P1.3	32	P1.3	D7	P1.3
46	P1.4	41	P1.4	39	P1.4			D4	P1.4
47	P1.5	42	P1.5					D5	P1.5
48	P1.6	43	P1.6					D6	P1.6
1	P1.7/VREF	44	P1.7/VREF	40	P1.7/VREF	1	P1.7/VREF	E7	P1.7/VRE
		1	VSSD						
2	P2.0	2	P2.0	1	P2.0	2	P2.0		
3	P2.1	3	P2.1	2	P2.1	3	P2.1		
4	P2.2	4	P2.2	3	P2.2	4	P2.2	D3	P2.2
5	P2.3	5	P2.3	4	P2.3	5	P2.3	E4	P2.3
6	P2.4	6	P2.4	5	P2.4			E5	P2.4
7	P2.5	7	P2.5	6	P2.5	6	P2.5	E6	P2.5
8	P2.6	8	P2.6	7	P2.6	7	P2.6	E3	P2.6
9	P2.7	9	P2.7	8	P2.7	8	P2.7	E2	P2.7
10	VSSD	10	VSSD	9	VSSD		1		
12	P3.0	11	P3.0	10	P3.0	9	P3.0	E1	P3.0
13	P3.1	12	P3.1	11	P3.1	10	P3.1	D2	P3.1
14	P3.2	13	P3.2	12	P3.2	11	P3.2	D1	P3.2
16	P3.3	14	P3.3	13	P3.3	12	P3.3	C1	P3.3
17	P3.4	15	P3.4	14	P3.4			C2	P3.4
18	P3.5	16	P3.5	15	P3.5				



Power

The following power system diagram shows the set of power supply pins as implemented for the PSoC 4100S. The system has one regulator in Active mode for the digital circuitry. There is no analog regulator; the analog circuits run directly from the V_{DD} input.

Figure 4. Power Supply Connections



There are two distinct modes of operation. In Mode 1, the supply voltage range is 1.8 V to 5.5 V (unregulated externally; internal regulator operational). In Mode 2, the supply range is 1.8 V ±5% (externally regulated; 1.71 to 1.89, internal regulator bypassed).

Mode 1: 1.8 V to 5.5 V External Supply

In this mode, the PSoC 4100S is powered by an external power supply that can be anywhere in the range of 1.8 to 5.5 V. This range is also designed for battery-powered operation. For example, the chip can be powered from a battery system that starts at 3.5 V and works down to 1.8 V. In this mode, the internal regulator of the PSoC 4100S supplies the internal logic and its output is connected to the $V_{\rm CCD}$ pin. The VCCD pin must be bypassed to ground via an external capacitor (0.1 μ F; X5R ceramic or better) and must not be connected to anything else.

Mode 2: 1.8 V ±5% External Supply

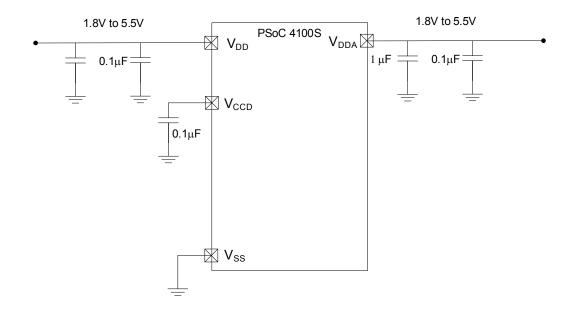
In this mode, the PSoC 4100S is powered by an external power supply that must be within the range of 1.71 to 1.89 V; note that this range needs to include the power supply ripple too. In this mode, the VDD and VCCD pins are shorted together and bypassed. The internal regulator can be disabled in the firmware.

Bypass capacitors must be used from VDDD to ground. The typical practice for systems in this frequency range is to use a capacitor in the 1- μ F range, in parallel with a smaller capacitor (0.1 μ F, for example). Note that these are simply rules of thumb and that, for critical applications, the PCB layout, lead inductance, and the bypass capacitor parasitic should be simulated to design and obtain optimal bypassing.

An example of a bypass scheme is shown in the following diagram.

Figure 5. External Supply Range from 1.8 V to 5.5 V with Internal Regulator Active

Power supply bypass connections example



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Development Support

The PSoC 4100S family has a rich set of documentation, development tools, and online resources to assist you during your development process. Visit www.cypress.com/go/psoc4 to find out more.

Documentation

A suite of documentation supports the PSoC 4100S family to ensure that you can find answers to your questions quickly. This section contains a list of some of the key documents.

Software User Guide: A step-by-step guide for using PSoC Creator. The software user guide shows you how the PSoC Creator build process works in detail, how to use source control with PSoC Creator, and much more.

Component Datasheets: The flexibility of PSoC allows the creation of new peripherals (components) long after the device has gone into production. Component data sheets provide all of the information needed to select and use a particular component, including a functional description, API documentation, example code, and AC/DC specifications.

Application Notes: PSoC application notes discuss a particular application of PSoC in depth; examples include brushless DC motor control and on-chip filtering. Application notes often include example projects in addition to the application note document.

Technical Reference Manual: The Technical Reference Manual (TRM) contains all the technical detail you need to use a PSoC device, including a complete description of all PSoC registers. The TRM is available in the Documentation section at www.cypress.com/psoc4.

Online

In addition to print documentation, the Cypress PSoC forums connect you with fellow PSoC users and experts in PSoC from around the world, 24 hours a day, 7 days a week.

Tools

With industry standard cores, programming, and debugging interfaces, the PSoC 4100S family is part of a development tool ecosystem. Visit us at www.cypress.com/go/psoccreator for the latest information on the revolutionary, easy to use PSoC Creator IDE, supported third party compilers, programmers, debuggers, and development kits.



Table 3. DC Specifications (continued)

Typical values measured at V_{DD} = 3.3 V and 25 °C.

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions		
Sleep Mode,	VDDD = 1.8 V to	5.5 V (Regulator on)							
SID22	IDD17	I ² C wakeup WDT, and Comparators on	_	1.7	2.2	mA	6 MHZ. Max is at 85 °C and 5.5 V.		
SID25	IDD20	I ² C wakeup, WDT, and Comparators on.	_	2.2	2.5		12 MHZ. Max is at 85 °C and 5.5 V.		
Sleep Mode,	V _{DDD} = 1.71 V to	o 1.89 V (Regulator bypassed)				· •			
SID28	IDD23	I ² C wakeup, WDT, and Comparators on	_	0.7	0.9	mA	6 MHZ. Max is at 85 °C and 5.5 V.		
SID28A	IDD23A	I ² C wakeup, WDT, and Comparators on	_	1	1.2	mA	12 MHZ. Max is at 85 °C and 5.5 V.		
Deep Sleep	Mode, V _{DD} = 1.8	V to 3.6 V (Regulator on)		•					
SID31	I _{DD26}	I ² C wakeup and WDT on	_	2.5	60	μA	Max is at 3.6 V and 85 °C.		
Deep Sleep	Mode, V _{DD} = 3.6	V to 5.5 V (Regulator on)				1			
SID34	I _{DD29}	I ² C wakeup and WDT on	_	2.5	60	μА	Max is at 5.5 V and 85 °C.		
Deep Sleep	Mode, V _{DD} = V _{CO}	_{CD} = 1.71 V to 1.89 V (Regulator bypasse	ed)			1			
SID37	I _{DD32}	I ² C wakeup and WDT on	_	2.5	65	μΑ	Max is at 1.89 V and 85 °C.		
XRES Current									
SID307	I _{DD_XR}	Supply current while XRES asserted	_	2	5	mA	_		

Table 4. AC Specifications

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID48	F _{CPU}	CPU frequency	DC	_	48	MHz	$1.71 \le V_{DD} \le 5.5$
SID49 ^[3]	T _{SLEEP}	Wakeup from Sleep mode	_	0	_	us	
SID50 ^[3]	T _{DEEPSLEEP}	Wakeup from Deep Sleep mode	_	35	1	μδ	

Note
2. Guaranteed by characterization.



GPIO

Table 5. GPIO DC Specifications

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID57	V _{IH} [3]	Input voltage high threshold	$0.7 \times V_{DDD}$	-	_		CMOS Input
SID58	V _{IL}	Input voltage low threshold	-	_	$0.3 \times V_{DDD}$		CMOS Input
SID241	V _{IH} [3]	LVTTL input, V _{DDD} < 2.7 V	$0.7 \times V_{DDD}$	-	_		_
SID242	V _{IL}	LVTTL input, V _{DDD} < 2.7 V	-	_	$0.3 \times V_{DDD}$		_
SID243	V _{IH} [3]	LVTTL input, $V_{DDD} \ge 2.7 \text{ V}$	2.0	-	_		_
SID244	V _{IL}	LVTTL input, $V_{DDD} \ge 2.7 \text{ V}$	_	-	8.0	V	_
SID59	V _{OH}	Output voltage high level	V _{DDD} -0.6	-	_		I_{OH} = 4 mA at 3 V V_{DDD}
SID60	V _{OH}	Output voltage high level	V _{DDD} -0.5	-	_		I _{OH} = 1 mA at 1.8 V V _{DDD}
SID61	V _{OL}	Output voltage low level	-	_	0.6		I _{OL} = 4 mA at 1.8 V V _{DDD}
SID62	V _{OL}	Output voltage low level	_	-	0.6		I_{OL} = 10 mA at 3 V V_{DDD}
SID62A	V _{OL}	Output voltage low level	-	-	0.4		I_{OL} = 3 mA at 3 V V_{DDD}
SID63	R _{PULLUP}	Pull-up resistor	3.5	5.6	8.5	kΩ	_
SID64	R _{PULLDOWN}	Pull-down resistor	3.5	5.6	8.5	N22	_
SID65	I _{IL}	Input leakage current (absolute value)	_	_	2	nA	25 °C, V _{DDD} = 3.0 V
SID66	C _{IN}	Input capacitance	_	-	7	pF	_
SID67 ^[4]	V _{HYSTTL}	Input hysteresis LVTTL	25	40	_		$V_{DDD} \ge 2.7 \text{ V}$
SID68 ^[4]	V _{HYSCMOS}	Input hysteresis CMOS	$0.05 \times V_{DDD}$	-	_	mV	V _{DD} < 4.5 V
SID68A ^[4]	V _{HYSCMOS5V5}	Input hysteresis CMOS	200	-	_		V _{DD} > 4.5 V
SID69 ^[4]	I _{DIODE}	Current through protection diode to V_{DD}/V_{SS}	-	_	100	μA	_
SID69A ^[4]	I _{TOT_GPIO}	Maximum total source or sink chip current	_	_	200	mA	-

Table 6. GPIO AC Specifications

(Guaranteed by Characterization)

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID70	T _{RISEF}	Rise time in fast strong mode	2	1	12		3.3 V V _{DDD} , Cload = 25 pF
SID71	T _{FALLF}	Fall time in fast strong mode	2	_	12		3.3 V V _{DDD} , Cload = 25 pF
SID72	T _{RISES}	Rise time in slow strong mode	10	_	60		3.3 V V _{DDD} , Cload = 25 pF

V_{IH} must not exceed V_{DDD} + 0.2 V.
 Guaranteed by characterization.



Table 6. GPIO AC Specifications

(Guaranteed by Characterization) (continued)

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID73	T _{FALLS}	Fall time in slow strong mode	10	-	60		3.3 V V _{DDD} , Cload = 25 pF
SID74	F _{GPIOUT1}	GPIO F_{OUT} ; 3.3 $V \le V_{DDD} \le 5.5 V$ Fast strong mode	_	_	33		90/10%, 25 pF load, 60/40 duty cycle
SID75	F _{GPIOUT2}	GPIO F _{OUT} ; 1.71 V≤ V _{DDD} ≤ 3.3 V Fast strong mode	_	-	16.7		90/10%, 25 pF load, 60/40 duty cycle
SID76	F _{GPIOUT3}	GPIO F_{OUT} ; 3.3 $V \le V_{DDD} \le 5.5 V$ Slow strong mode	_	-	7	MHz	90/10%, 25 pF load, 60/40 duty cycle
SID245	F _{GPIOUT4}	GPIO F_{OUT} ; 1.71 $V \le V_{DDD} \le 3.3 V$ Slow strong mode.	_	-	3.5		90/10%, 25 pF load, 60/40 duty cycle
SID246	F _{GPIOIN}	GPIO input operating frequency; 1.71 V \leq V _{DDD} \leq 5.5 V	_	-	48		90/10% V _{IO}

XRES

Table 7. XRES DC Specifications

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions	
SID77	V _{IH}	Input voltage high threshold	$0.7 \times V_{DDD}$	_	_	V	CMOS Input	
SID78	V _{IL}	Input voltage low threshold	_	_	$0.3 \times V_{DDD}$	V	CiviOS input	
SID79	R _{PULLUP}	Pull-up resistor	_	60	-	kΩ	-	
SID80	C _{IN}	Input capacitance	_	_	7	pF	-	
SID81 ^[5]	V _{HYSXRES}	Input voltage hysteresis	-	100	_	mV	Typical hysteresis is 200 mV for V _{DD} > 4.5 V	
SID82	I _{DIODE}	Current through protection diode to V _{DD} /V _{SS}	_	-	100	μΑ		

Table 8. XRES AC Specifications

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID83 ^[5]	T _{RESETWIDTH}	Reset pulse width	1	_	_	μs	-
BID194 ^[5]	T _{RESETWAKE}	Wake-up time from reset release	_	-	2.7	ms	_

Note
5. Guaranteed by characterization.



Analog Peripherals

Table 9. CTBm Opamp Specifications

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
	I _{DD}	Opamp block current, External load					
SID269	I _{DD_HI}	power=hi	-	1100	1850		-
SID270	I _{DD_MED}	power=med	-	550	950	μA	_
SID271	I _{DD_LOW}	power=lo	1	150	350		_
	G _{BW}	Load = 20 pF, 0.1 mA V _{DDA} = 2.7 V					
SID272	G _{BW_HI}	power=hi	6	_	_		Input and output are 0.2 V to V _{DDA} -0.2 V
SID273	G _{BW_MED}	power=med	3	-	_	MHz	Input and output are 0.2 V to V _{DDA} -0.2 V
SID274	G _{BW_LO}	power=lo	-	1	_		Input and output are 0.2 V to V _{DDA} -0.2 V
	I _{OUT_MAX}	$V_{DDA} = 2.7 \text{ V}, 500 \text{ mV from rail}$, ,			
SID275	I _{OUT_MAX_HI}	power=hi	10	-	_		Output is 0.5 V V _{DDA} -0.5 V
SID276	I _{OUT_MAX_MID}	power=mid	10	-	_	mA	Output is 0.5 V V _{DDA} -0.5 V
SID277	I _{OUT_MAX_LO}	power=lo	-	5	_		Output is 0.5 V V _{DDA} -0.5 V
	I _{OUT}	V_{DDA} = 1.71 V, 500 mV from rail					
SID278	I _{OUT_MAX_HI}	power=hi	4	-	-		Output is 0.5 V V _{DDA} -0.5 V
SID279	I _{OUT_MAX_MID}	power=mid	4	_	-	mA	Output is 0.5 V V _{DDA} -0.5 V
SID280	I _{OUT_MAX_LO}	power=lo	ı	2	_		Output is 0.5 V V _{DDA} -0.5 V
	I _{DD_Int}	Opamp block current Internal Load					
SID269_I	I _{DD_HI_Int}	power=hi	ı	1500	1700		_
SID270_I	I _{DD_MED_Int}	power=med	_	700	900	μA	_
CIDO74	I _{DD_LOW_Int}	power=lo	-	-	_		-
SID271_I	G _{BW}	V _{DDA} = 2.7 V	-	_	-		-
SID272_I	G _{BW_HI_Int}	power=hi	8	-	_	MHz	Output is 0.25 V to V _{DDA} -0.25 V



Table 9. CTBm Opamp Specifications (continued)

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions	
		General opamp specs for both internal and external modes						
SID281	V _{IN}	Charge-pump on, $V_{DDA} = 2.7 \text{ V}$	-0.05	-	V _{DDA} -0.2	V	_	
SID282	V _{CM}	Charge-pump on, V _{DDA} = 2.7 V	-0.05	_	V _{DDA} -0.2		_	
	V _{OUT}	V _{DDA} = 2.7 V		l	•		,	
SID283	V _{OUT_1}	power=hi, Iload=10 mA	0.5	_	V _{DDA} -0.5		_	
SID284	V _{OUT_2}	power=hi, Iload=1 mA	0.2	_	V _{DDA} -0.2	V	_	
SID285	V _{OUT_3}	power=med, Iload=1 mA	0.2	_	V _{DDA} -0.2	v	_	
SID286	V _{OUT_4}	power=lo, Iload=0.1 mA	0.2	_	V _{DDA} -0.2		_	
SID288	V _{OS_TR}	Offset voltage, trimmed	-1.0	±0.5	1.0		High mode, input 0 V to V _{DDA} -0.2 V	
SID288A	V _{OS_TR}	Offset voltage, trimmed	_	±1	_	mV	Medium mode, input 0 V to V _{DDA} -0.2 V	
SID288B	V _{OS_TR}	Offset voltage, trimmed	-	±2	_		Low mode, input 0 V to V _{DDA} -0.2 V	
SID290	V _{OS_DR_TR}	Offset voltage drift, trimmed	-10	±3	10	μV/C	High mode	
SID290A	V _{OS_DR_TR}	Offset voltage drift, trimmed	-	±10	_	μV/C	Medium mode	
SID290B	V _{OS_DR_TR}	Offset voltage drift, trimmed	_	±10	_	μν/Ο	Low mode	
SID291	CMRR	DC	70	80	_		Input is 0 V to V _{DDA} -0.2 V, Output is 0.2 V to V _{DDA} -0.2 V	
SID292	PSRR	At 1 kHz, 10-mV ripple	70	85	-	dB	V _{DDD} = 3.6 V, high-power mode, input is 0.2 V to V _{DDA} -0.2 V	
	Noise							
SID294	VN2	Input-referred, 1 kHz, power=Hi	_	72	_		3	
SID295	VN3	Input-referred, 10 kHz, power=Hi	-	28	_	nV/rtHz	Input and output are at 0.2 V to V _{DDA} -0.2 V	
SID296	VN4	Input-referred, 100 kHz, power=Hi	-	15	_		Input and output are at 0.2 V to V _{DDA} -0.2 V	
SID297	C _{LOAD}	Stable up to max. load. Performance specs at 50 pF.	-	-	125	pF	-	
SID298	SLEW_RATE	Cload = 50 pF, Power = High, V _{DDA} = 2.7 V	6	-	_	V/µs	_	



Table 10. Comparator DC Specifications

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID84	V _{OFFSET1}	Input offset voltage, Factory trim	_	_	±10		
SID85	V _{OFFSET2}	Input offset voltage, Custom trim	_	_	±4	mV	
SID86	V _{HYST}	Hysteresis when enabled	_	10	35		
SID87	V _{ICM1}	Input common mode voltage in normal mode	0	_	V _{DDD} -0.1		Modes 1 and 2
SID247	V _{ICM2}	Input common mode voltage in low power mode	0	_	V_{DDD}	V	
SID247A	V _{ICM3}	Input common mode voltage in ultra low power mode	0	-	V _{DDD} -1.15	·	V _{DDD} ≥ 2.2 V at -40 °C
SID88	C _{MRR}	Common mode rejection ratio	50	_	_	dB	V _{DDD} ≥ 2.7V
SID88A	C _{MRR}	Common mode rejection ratio	42	_	-	uБ	V _{DDD} ≤ 2.7V
SID89	I _{CMP1}	Block current, normal mode	_	_	400		
SID248	I _{CMP2}	Block current, low power mode	_	_	100	μA	
SID259	I _{CMP3}	Block current in ultra low-power mode	-	-	6	, h.,	V _{DDD} ≥ 2.2 V at –40 °C
SID90	Z _{CMP}	DC Input impedance of comparator	35	_	_	ΜΩ	

Table 11. Comparator AC Specifications

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID91	TRESP1	Response time, normal mode, 50 mV overdrive	-	38	110		
SID258	TRESP2	Response time, low power mode, 50 mV overdrive	-	70	200	ns	
SID92	TRESP3	Response time, ultra-low power mode, 200 mV overdrive	-	2.3	15	μs	V _{DDD} ≥ 2.2 V at -40 °C

Table 12. Temperature Sensor Specifications

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details / Conditions
SID93	TSENSACC	Temperature sensor accuracy	- 5	±1	5	°C	–40 to +85 °C

Table 13. SAR Specifications

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SAR ADC	DC Specificat	ions				•	
SID94	A_RES	Resolution	-	_	12	bits	
SID95	A_CHNLS_S	Number of channels - single ended	-	_	16		
SID96	A-CHNKS_D	Number of channels - differential	-	-	4		Diff inputs use neighboring I/O
SID97	A-MONO	Monotonicity	-	-	_		Yes.
SID98	A_GAINERR	Gain error	-	_	±0.1	%	With external reference.

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CSD

Table 14. CSD and IDAC Specifications

SPEC ID#	Parameter	Description	Min	Тур	Max	Units	Details / Conditions
SYS.PER#3	VDD_RIPPLE	Max allowed ripple on power supply, DC to 10 MHz	ı	_	±50	mV	V _{DD} > 2 V (with ripple), 25 °C T _A , Sensitivity = 0.1 pF
SYS.PER#16	VDD_RIPPLE_1.8	Max allowed ripple on power supply, DC to 10 MHz	-	_	±25	mV	V_{DD} > 1.75V (with ripple), 25 °C T _A , Parasitic Capacitance (C _P) < 20 pF, Sensitivity ≥ 0.4 pF
SID.CSD.BLK	ICSD	Maximum block current	-	-	4000	μA	Maximum block current for both IDACs in dynamic (switching) mode including comparators, buffer, and reference generator.
SID.CSD#15	V _{REF}	Voltage reference for CSD and Comparator	0.6	1.2	V _{DDA} - 0.6	V	V _{DDA} - 0.06 or 4.4, whichever is lower
SID.CSD#15A	VREF_EXT	External Voltage reference for CSD and Comparator	0.6		V _{DDA} - 0.6	V	V _{DDA} - 0.06 or 4.4, whichever is lower
SID.CSD#16	IDAC1IDD	IDAC1 (7-bits) block current	_	-	1750	μΑ	
SID.CSD#17	IDAC2IDD	IDAC2 (7-bits) block current	_	-	1750	μΑ	
SID308	VCSD	Voltage range of operation	1.71	-	5.5	V	1.8 V ±5% or 1.8 V to 5.5 \
SID308A	VCOMPIDAC	Voltage compliance range of IDAC	0.6	-	V _{DDA} -0.6	V	V _{DDA} - 0.06 or 4.4, whichever is lower
SID309	IDAC1DNL	DNL	-1	-	1	LSB	
SID310	IDAC1INL	INL	-2	_	2	LSB	INL is ± 5.5 LSB for $V_{DDA} < 2$ V
SID311	IDAC2DNL	DNL	-1	-	1	LSB	
SID312	IDAC2INL	INL	-2	_	2	LSB	INL is ± 5.5 LSB for $V_{DDA} < 2$ V
SID313	SNR	Ratio of counts of finger to noise. Guaranteed by characterization	5	_	_	Ratio	Capacitance range of 5 to 35 pF, 0.1-pF sensitivity. All use cases. V _{DDA} > 2 V.
SID314	IDAC1CRT1	Output current of IDAC1 (7 bits) in low range	4.2	_	5.4	μA	LSB = 37.5-nA typ.
SID314A	IDAC1CRT2	Output current of IDAC1(7 bits) in medium range	34	_	41	μA	LSB = 300-nA typ.
SID314B	IDAC1CRT3	Output current of IDAC1(7 bits) in high range	275	_	330	μA	LSB = 2.4-μA typ.
SID314C	IDAC1CRT12	Output current of IDAC1 (7 bits) in low range, 2X mode	8	-	10.5	μA	LSB = 75-nA typ.
SID314D	IDAC1CRT22	Output current of IDAC1(7 bits) in medium range, 2X mode	69	-	82	μA	LSB = 600-nA typ.
SID314E	IDAC1CRT32	Output current of IDAC1(7 bits) in high range, 2X mode	540	-	660	μA	LSB = 4.8-μA typ.
SID315	IDAC2CRT1	Output current of IDAC2 (7 bits) in low range	4.2	_	5.4	μA	LSB = 37.5-nA typ.
SID315A	IDAC2CRT2	Output current of IDAC2 (7 bits) in medium range	34	_	41	μA	LSB = 300-nA typ.
SID315B	IDAC2CRT3	Output current of IDAC2 (7 bits) in high range	275	_	330	μA	LSB = 2.4-µA typ.
SID315C	IDAC2CRT12	Output current of IDAC2 (7 bits) in low range, 2X mode	8	_	10.5	μA	LSB = 75-nA typ.
SID315D	IDAC2CRT22	Output current of IDAC2(7 bits) in medium range, 2X mode	69	_	82	μA	LSB = 600-nA typ.
SID315E	IDAC2CRT32	Output current of IDAC2(7 bits) in high range, 2X mode	540	_	660	μA	LSB = 4.8-μA typ.
SID315F	IDAC3CRT13	Output current of IDAC in 8-bit mode in low range	8	_	10.5	μA	LSB = 37.5-nA typ.



Table 15. 10-bit CapSense ADC Specifications (continued)

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SIDA109	A_SND	Signal-to-noise and Distortion ratio (SINAD)	_	61	-		With 10-Hz input sine wave, external 2.4-V reference, V _{REF} (2.4 V) mode
SIDA110	A_BW	Input bandwidth without aliasing	_	_	22.4	KHz	8-bit resolution
SIDA111	A_INL	Integral Non Linearity. 1 ksps	-	_	2	LSB	V _{REF} = 2.4 V or greater
SIDA112	A_DNL	Differential Non Linearity. 1 ksps	_	_	1	LSB	

Digital Peripherals

Timer Counter Pulse-Width Modulator (TCPWM)

Table 16. TCPWM Specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID.TCPWM.1	ITCPWM1	Block current consumption at 3 MHz	_	-	45		All modes (TCPWM)
SID.TCPWM.2	ITCPWM2	Block current consumption at 12 MHz	_	-	155	μΑ	All modes (TCPWM)
SID.TCPWM.2A	ITCPWM3	Block current consumption at 48 MHz	_	-	650		All modes (TCPWM)
SID.TCPWM.3	TCPWM _{FREQ}	Operating frequency	_	_	Fc	MHz	Fc max = CLK_SYS Maximum = 48 MHz
SID.TCPWM.4	TPWM _{ENEXT}	Input trigger pulse width	2/Fc	-	_		For all trigger events ^[7]
SID.TCPWM.5	TPWM _{EXT}	Output trigger pulse widths	2/Fc	-	_		Minimum possible width of Overflow, Underflow, and CC (Counter equals Compare value) outputs
SID.TCPWM.5A	TC _{RES}	Resolution of counter	1/Fc	1	-	ns	Minimum time between successive counts
SID.TCPWM.5B	PWM _{RES}	PWM resolution	1/Fc	ı	-		Minimum pulse width of PWM Output
SID.TCPWM.5C	Q _{RES}	Quadrature inputs resolution	1/Fc	_	_		Minimum pulse width between Quadrature phase inputs

РC

Table 17. Fixed I²C DC Specifications^[8]

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID149	I _{I2C1}	Block current consumption at 100 kHz	-	_	50		_
SID150	I _{I2C2}	Block current consumption at 400 kHz	-	_	135	μΑ	-
SID151	I _{I2C3}	Block current consumption at 1 Mbps	-	_	310		-
SID152	I _{I2C4}	I ² C enabled in Deep Sleep mode	_	_	1.4		

Table 18. Fixed I²C AC Specifications^[8]

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID153	F _{I2C1}	Bit rate	_	_	1	Msps	-

Notes

Note

^{7.} Trigger events can be Stop, Start, Reload, Count, Capture, or Kill depending on which mode of operation is selected.

^{8.} Guaranteed by characterization.



Table 34. Watch Crystal Oscillator (WCO) Specifications

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details / Conditions
SID398	FWCO	Crystal Frequency	-	32.768	_	kHz	
SID399	FTOL	Frequency tolerance	-	50	250	ppm	With 20-ppm crystal
SID400	ESR	Equivalent series resistance	-	50	_	kΩ	
SID401	PD	Drive Level	-	_	1	μW	
SID402	TSTART	Startup time	-	_	500	ms	
SID403	CL	Crystal Load Capacitance	6	_	12.5	pF	
SID404	C0	Crystal Shunt Capacitance	-	1.35	_	pF	
SID405	IWCO1	Operating Current (high power mode)	_	_	8	uA	
SID406	IWCO2	Operating Current (low power mode)	-	_	1	uA	

Table 35. External Clock Specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
	•	External clock input frequency	0	_	48	MHz	_
SID306 ^[13]	ExtClkDuty	Duty cycle; measured at V _{DD/2}	45	_	55	%	-

Table 36. Block Specs

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID262 ^[13]	T _{CLKSWITCH}	System clock source switching time	3	1	4	Periods	_

Table 37. Smart I/O Pass-through Time (Delay in Bypass Mode)

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details / Conditions
SID252	PRG_BYPASS	Max delay added by Smart I/O in bypass mode	-	1	1.6	ns	

Note 13. Guaranteed by characterization.



Ordering Information

The marketing part numbers for the PSoC 4100S family are listed in the following table.

	MPN	Features								Package									
Category		Max CPU Speed (MHz)	Flash (KB)	SRAM (KB)	Opamp (CTBm)	CSD	10-bit CSD ADC	12-bit SAR ADC	ADC Sample Rate	LP Comparators	TCPWM Blocks	SCB Blocks	Smart I/Os	GPIO	35-WLCSP (0.35mm pitch)	32-QFN	40-QFN	48-TQFP	44-TQFP
	CY8C4124FNI-S403	24	16	4	2	0	1	0		2	5	2	8	31	Χ				
	CY8C4124FNI-S413	24	16	4	2	1	1	0		2	5	2	16	31	Х				
	CY8C4124LQI-S412	24	16	4	2	1	1	0		2	5	2	16	27		Х			
	CY8C4124LQI-S413	24	16	4	2	1	1	0		2	5	2	16	34			Х		
4124	CY8C4124AZI-S413	24	16	4	2	1	1	0		2	5	2	16	36				Х	
	CY8C4124FNI-S433	24	16	4	2	1	1	1	806 ksps	2	5	2	16	31	Х				
	CY8C4124LQI-S432	24	16	4	2	1	1	1	806 ksps	2	5	2	16	27		Х			
	CY8C4124LQI-S433	24	16	4	2	1	1	1	806 ksps	2	5	2	16	34			Х		
	CY8C4124AZI-S433	24	16	4	2	1	1	1	806 ksps	2	5	2	16	36				Х	
	CY8C4125FNI-S423	24	32	4	2	0	1	1	806 ksps	2	5	2	16	31	Х				
•	CY8C4125LQI-S422	24	32	4	2	0	1	1	806 ksps	2	5	2	16	27		Х			
-	CY8C4125LQI-S423	24	32	4	2	0	1	1	806 ksps	2	5	2	16	34			Х		
-	CY8C4125AZI-S423	24	32	4	2	0	1	1	806 ksps	2	5	2	16	36				Х	
-	CY8C4125AXI-S423	24	32	4	2	0	1	1	806 ksps	2	5	2	16	36					Х
-	CY8C4125FNI-S413	24	32	4	2	1	1	0		2	5	2	16	31	Х				
	CY8C4125LQI-S412	24	32	4	2	1	1	0		2	5	2	16	27		Х			
4125	CY8C4125LQI-S413	24	32	4	2	1	1	0		2	5	2	16	34			Х		
-	CY8C4125AZI-S413	24	32	4	2	1	1	0		2	5	2	16	36				Х	
	CY8C4125FNI-S433	24	32	4	2	1	1	1	806 ksps	2	5	2	16	31	Х				
	CY8C4125LQI-S432	24	32	4	2	1	1	1	806 ksps	2	5	2	16	27		Х			
	CY8C4125LQI-S433	24	32	4	2	1	1	1	806 ksps	2	5	2	16	34			Х		
	CY8C4125AZI-S433	24	32	4	2	1	1	1	806 ksps	2	5	2	16	36				Х	
	CY8C4125AXI-S433	24	32	4	2	1	1	1	806 ksps	2	5	2	16	36					Х
	CY8C4126AZI-S423	24	64	8	2	0	1	1	806 ksps	2	5	3	16	36				Х	
	CY8C4126AXI-S423	24	64	8	2	0	1	1	806 ksps	2	5	3	16	36					Х
4126	CY8C4126AZI-S433	24	64	8	2	1	1	1	806 ksps	2	5	3	16	36				Х	
	CY8C4126AXI-S433	24	64	8	2	1	1	1	806 ksps	2	5	3	16	36					Х
	CY8C4145AZI-S423	48	32	4	2	0	1	1	1 Msps	2	5	2	16	36				Х	
4145	CY8C4145AXI-S423	48	32	4	2	0	1	1	1 Msps	2	5	2	16	36					Х
	CY8C4145AXI-S433	48	32	4	2	1	1	1	1 Msps	2	5	2	16	36					Х
4146	CY8C4146FNI-S423	48	64	8	2	0	1	1	1 Msps	2	5	3	16	31	Х				
	CY8C4146LQI-S422	48	64	8	2	0	1	1	1 Msps	2	5	3	16	27		Х			
	CY8C4146LQI-S423	48	64	8	2	0	1	1	1 Msps	2	5	3	16	34			Х		\vdash
	CY8C4146AZI-S423	48	64	8	2	0	1	1	1 Msps	2	5	3	16	36				Х	
	CY8C4146AXI-S423	48	64	8	2	0	1	1	1 Msps	2	5	3	16	36					Х
	CY8C4146FNI-S433	48	64	8	2	1	1	1	1 Msps	2	5	3	16	31	Х				
	CY8C4146LQI-S432	48	64	8	2	1	1	1	1 Msps	2	5	3	16	27		Х			\vdash
	CY8C4146LQI-S433	48	64	8	2	1	1	1	1 Msps	2	5	3	16	34			Х		\vdash
	CY8C4146AZI-S433	48	64	8	2	1	1	1	1 Msps	2	5	3	16	36				Х	\vdash
	CY8C4146AXI-S433	48	64	8	2	1	1	1	1 Msps	2	5	3	16	36					Х



Packaging

The PSoC 4100S will be offered in 48-pin TQFP, 44-pin TQFP, 40-pin QFN, 32-pin QFN, and 35-ball WLCSP packages. Package dimensions and Cypress drawing numbers are in the following table.

Table 38. Package List

Spec ID#	Package	Description	Package Dwg
BID20	48-pin TQFP	7 × 7 × 1.4-mm height with 0.5-mm pitch	51-85135
BID20A	44-pin TQFP	10 × 10 × 1.6-mm height with 0.8-mm pitch	51-85064
BID27	40-pin QFN	6 × 6 × 0.6-mm height with 0.5-mm pitch	001-80659
BID34A	32-pin QFN	5 × 5 × 0.6-mm height with 0.5-mm pitch	001-42168
BID34D	35-ball WLCSP	2.6 × 2.1 × 0.48-mm height with 0.35-mm pitch	002-09958

Table 39. Package Thermal Characteristics

Parameter	Description	Package	Min	Тур	Max	Units
TA	Operating Ambient temperature		-40	25	85	°C
TJ	Operating junction temperature		-40	_	100	°C
TJA	Package θ _{JA}	48-pin TQFP	-	74.8	-	°C/Watt
TJC	Package θ _{JC}	48-pin TQFP	-	35.7	-	°C/Watt
TJA	Package θ _{JA}	44-pin TQFP	_	57.2	_	°C/Watt
TJC	Package θ_{JC}	44-pin TQFP	_	17.5	_	°C/Watt
TJA	Package θ _{JA}	40-pin QFN	-	17.8	-	°C/Watt
TJC	Package θ_{JC}	40-pin QFN	_	2.8	_	°C/Watt
TJA	Package θ_{JA}	32-pin QFN	_	19.9	_	°C/Watt
TJC	Package θ _{JC}	32-pin QFN	-	4.3	-	°C/Watt
TJA	Package θ _{JA}	35-ball WLCSP	_	43	_	°C/Watt
TJC	Package θ_{JC}	35-ball WLCSP	_	0.3	-	°C/Watt

Table 40. Solder Reflow Peak Temperature

Package	Maximum Peak Temperature	Maximum Time at Peak Temperature					
All	260 °C	30 seconds					

Table 41. Package Moisture Sensitivity Level (MSL), IPC/JEDEC J-STD-020

Package	MSL
All except WLCSP	MSL 3
35-ball WLCSP	MSL 1

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Package Diagrams

Figure 6. 48-pin TQFP Package Outline

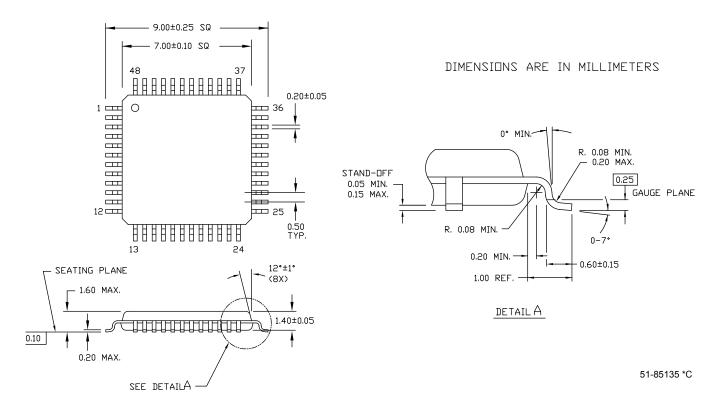
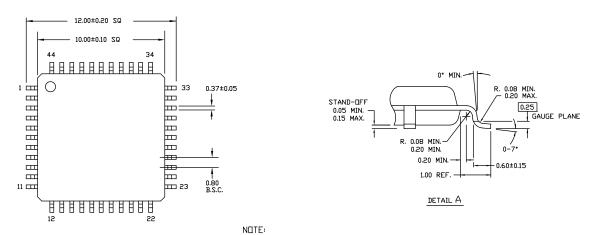


Figure 7. 44-pin TQFP Package Outline



SEATING PLANE

1.60 MAX.

1.40±0.05

0.20 MAX.

SEE DETAILA

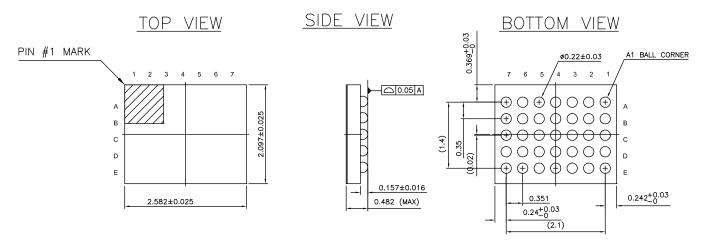
1. JEDEC STD REF MS-026

- 2. BODY LENGTH DIMENSION DOES NOT INCLUDE MOLD PROTRUSION/END FLASH
 MOLD PROTRUSION/END FLASH SHALL NOT EXCEED 0.0098 in (0.25 mm) PER SIDE
 BODY LENGTH DIMENSIONS ARE MAX PLASTIC BODY SIZE INCLUDING MOLD MISMATCH
- 3. DIMENSIONS IN MILLIMETERS

51-85064 *G



Figure 10. 35-Ball WLCSP Package Outline



ALL DIMENSIONS ARE IN MM JEDEC Publication 95; Design Guide 4.18 002-09958 *C



Table 42. Acronyms Used in this Document (continued)

Acronym	Description
PC	program counter
PCB	printed circuit board
PGA	programmable gain amplifier
PHUB	peripheral hub
PHY	physical layer
PICU	port interrupt control unit
PLA	programmable logic array
PLD	programmable logic device, see also PAL
PLL	phase-locked loop
PMDD	package material declaration data sheet
POR	power-on reset
PRES	precise power-on reset
PRS	pseudo random sequence
PS	port read data register
PSoC [®]	Programmable System-on-Chip™
PSRR	power supply rejection ratio
PWM	pulse-width modulator
RAM	random-access memory
RISC	reduced-instruction-set computing
RMS	root-mean-square
RTC	real-time clock
RTL	register transfer language
RTR	remote transmission request
RX	receive
SAR	successive approximation register
SC/CT	switched capacitor/continuous time
SCL	I ² C serial clock
SDA	I ² C serial data
S/H	sample and hold
SINAD	signal to noise and distortion ratio
SIO	special input/output, GPIO with advanced features. See GPIO.
SOC	start of conversion
SOF	start of frame
SPI	Serial Peripheral Interface, a communications protocol
SR	slew rate
SRAM	static random access memory
SRES	software reset
SWD	serial wire debug, a test protocol

Table 42. Acronyms Used in this Document (continued)

Acronym	Description
SWV	single-wire viewer
TD	transaction descriptor, see also DMA
THD	total harmonic distortion
TIA	transimpedance amplifier
TRM	technical reference manual
TTL	transistor-transistor logic
TX	transmit
UART	Universal Asynchronous Transmitter Receiver, a communications protocol
UDB	universal digital block
USB	Universal Serial Bus
USBIO	USB input/output, PSoC pins used to connect to a USB port
VDAC	voltage DAC, see also DAC, IDAC
WDT	watchdog timer
WOL	write once latch, see also NVL
WRES	watchdog timer reset
XRES	external reset I/O pin
XTAL	crystal

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